

# Gate Driver Providing Galvanic isolation Series Isolation voltage 2500Vrms 1ch Gate Driver Providing Galvanic Isolation

## BM6101FV-C

## General Description

The BM6101FV-C is a gate driver with isolation voltage 2500Vrms, I/O delay time of 350ns, and minimum input pulse width of 180ns, and incorporates the fault signal output functions, undervoltage lockout (UVLO) function, thermal protection function, and short current protection (SCP, DESAT) function.

#### Features

- Providing Galvanic Isolation
- Active Miller Clamping
- Fault signal output function
- (Adjustable output holding time)
   Undervoltage lockout function
- Thermal protection function
- Short current protection function (Adjustable reset time)
- Soft turn-off function for short current protection (Adjustable turn-off time)
- Supporting Negative VEE
- UL1577 Recognized:File No. E356010
- AEC-Q100 Qualified<sup>(Note 1)</sup>
- (Note 1:Grade1)

Typical Application Circuits

#### •Key Specifications

- Isolation voltage:
- Maximum gate drive voltage:
- I/O delay time:
- Minimum input pulse width:

2500Vrms(Max.) 24V(Max.) 350ns(Max.) 180ns(Max.)

## Package

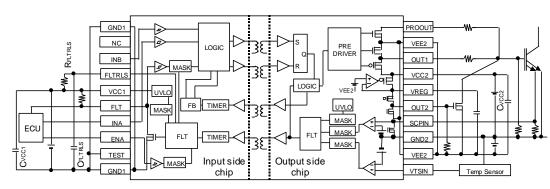
SSOP-B20W

W(Typ.) x D(Typ.) x H(Max.) 6.50mm x 8.10mm x 2.01mm



Applications

- Automotive isolated IGBT/MOSFET inverter gate drive
- Automotive DC-DC converter
- Industrial inverters system
- UPS system





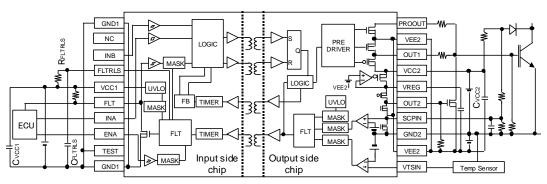


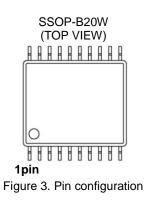
Figure 2. For using 3-pin IGBT (for using DESAT function)

#### OProduct structure : Silicon integrated circuit OThis product is not designed protection against radioactive rays

Recommended range of external constants

Pin Name	Symbol	Recor	nmended	Unit	
Fill Name	Symbol	Min.	Тур.	Max.	Unit
FLTRLS	CFLTRLS	-	0.01	0.47	uF
FLIKLS	RFLTRLS	50	200	1000	kΩ
VREG	CVREG	1.0	3.3	10.0	uF
VCC1	CVCC1	0.1	1.0	-	uF
VCC2	CVCC2	0.33	-	-	uF

## Pin Configuration



## Pin Description

Pin No.	Pin Name	Function
1	VTSIN	Thermal detection pin
2	VEE2	Output-side negative power supply pin
3	GND2	Output-side ground pin
4	SCPIN	Short current detection pin
5	OUT2	MOS FET control pin for Miller Clamp
6	VREG	Power supply pin for driving MOS FET for Miller Clamp
7	VCC2	Output-side positive power supply pin
8	OUT1	Output pin
9	VEE2	Output-side negative power supply pin
10	PROOUT	Soft turn-off pin
11	GND1	Input-side ground pin
12	NC	No Connect
13	INB	Invert / non-invert selection pin
14	FLTRLS	Fault output holding time setting pin
15	VCC1	Input-side power supply pin
16	FLT	Fault output pin
17	INA	Control input pin
18	ENA	Input enabling signal input pin
19	TEST	Mode setting pin
20	GND1	Input-side ground pin

#### Description of pins and cautions on layout of board

1) VCC1 (Input-side power supply pin)

The VCC1 pin is a power supply pin on the input side. To suppress voltage fluctuations due to the current to drive internal transformers, connect a bypass capacitor between the VCC1 and the GND1 pins.

- 2) GND1 (Input-side ground pin) The GND1 pin is a ground pin on the input side.
- 3) VCC2 (Output-side positive power supply pin)

The VCC2 pin is a positive power supply pin on the output side. To reduce voltage fluctuations due to OUT1 pin output current and due to the current to drive internal transformers, connect a bypass capacitor between the VCC2 and the GND2 pins.

4) VEE2 (Output-side negative power supply pin)

The VEE2 pin is a power supply pin on the output side. To suppress voltage fluctuations due to OUT1 pin output current and due to the current to drive internal transformers, connect a bypass capacitor between the VEE2 and the GND2 pins. To use no negative power supply, connect the VEE2 pin to the GND2 pin.

5) GND2 (Output-side ground pin)

The GND2 pin is a ground pin on the output side. Connect the GND2 pin to the emitter / source of a power device.

6) IN (Control input terminal)

The IN pin is a pin used to determine output logic.

EN	A	INB	INA	OUT1
Н		Х	Х	L
L		L	L	L
L		L	Н	Н
L		Н	L	Н
L		Н	Н	L

## 7) FLT (Fault output pin)

The FLT pin is an open drain pin used to output a fault signal when a fault occurs (i.e., when the undervoltage lockout function (UVLO), short current protection function (SCP) or thermal protection function is activated).

This pin is I/O pin and if L voltage is externally input, the output is set to L status regardless of other input logic.

Consequently, be sure to connect the pull-up resistor between VCC1 pin and the FLT pin even if this pin is not used.

Pin	FLT
While in normal operation	Hi-Z
When an Fault occurs	I
(When UVLO, SCP or thermal protection is activated)	L

#### 8) FLTRLS (Fault output holding time setting pin)

The FLTRLS pin is a pin used to make setting of time to hold a Fault signal. Connect a capacitor between the FLTRLS pin and the GND1 pin, and a resistor between it and the VCC1 pin.

The Fault signal is held until the FLTRLS pin voltage exceeds a voltage set with the VFLTRLS parameter. To set holding time to 0 ms, do not connect the capacitor. Short-circuiting the FLTRLS pin to the VCC1 pin will cause a high current to flow in the FLTRLS pin and, in an open state, may cause the IC to malfunction. To avoid such trouble, be sure to connect a resistor between the FLTRLS and the VCC1 pins.

9) OUT1 (Output pin)

The OUT1 pin is a pin used to drive the gate of a power device.

10) OUT2 (MOS FET control pin for Miller Clamp)

The OUT2 pin is a pin for controlling the external MOS switch for preventing increase in gate voltage due to the miller current of the power device connected to OUT1 pin.

11) VREG (Power supply pin for driving MOS FET for Miller Clamp)

The VREG pin is a power supply pin for driving MOS FET for Miller Clamp. Be sure to connect a capacitor between VREG pin and VEE2 pin for preventing the oscillation and to reduce voltage fluctuations due to OUT2 pin output current.

12) PROOUT (Soft turn-off pin)

The PROOUT pin is a pin used to put the soft turn-off function of a power devise in operation when the SCP function is activated. This pin combines with the gate voltage monitoring pin for Miller Clamp.

13) SCPIN (Short current detection pin)

The SCPIN pin is a pin used to detect current for short current protection. When the SCPIN pin voltage exceeds a voltage set with the VSCDET parameter, the SCP function will be activated. This may cause the IC to malfunction in an open state. To avoid such trouble, short-circuit the SCPIN pin to the GND2 pin if the short current protection is not used. In order to prevent the wrong detection due to noise, the noise mask time t<sub>SCPMSK</sub> is set.

## 14) VTSIN (Thermal detection pin)

The VTSIN pin is a temperature sensor voltage input pin, which can be used for thermal protection of an output device. If VTSIN pin voltage becomes VTSDET or less, OUT pin is set to L. In the open status, the IC may malfunction, so be sure to supply the VTSPIN more than  $V_{TSDET}$  if the thermal protection function is not used. In order to prevent the wrong detection due to noise, the noise mask time  $t_{TSMSK}$  is set.

#### 15) TEST(Mode setting pin)

The TEST pin is an operation mode setting pin. This pin is usually connected to GND1 pin. If the TEST pin is connected to the VCC1 pin, Input-side UVLO function is disabled.

#### Description of functions and examples of constant setting

#### 1) Miller Clamp function

When OUT1=L and PROOUT pin voltage < V<sub>OUT2ON</sub>, H is output from OUT2 pin and the external MOS switch is turned ON. When OUT1=H, L is output from OUT2 pin and the external MOS switch is turned OFF. While the short-circuit protection function is activated, L is output from OUT2 pin and the external MOS switch is turned OFF.

Short current	SCPIN	IN	PROOUT	OUT2
Detected	Not less than VSCDET	Х	Х	L
	Х	L	Not less than VOUT2ON	Hi-Z
Not detected	Х	L	Not more than $V_{OUT2ON}$	н
	Х	Н	Х	L

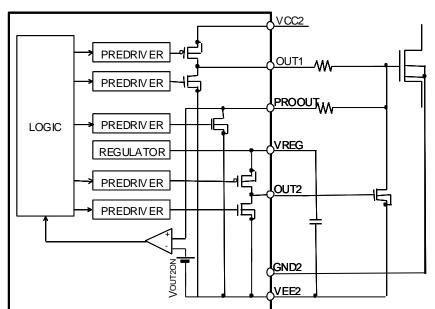
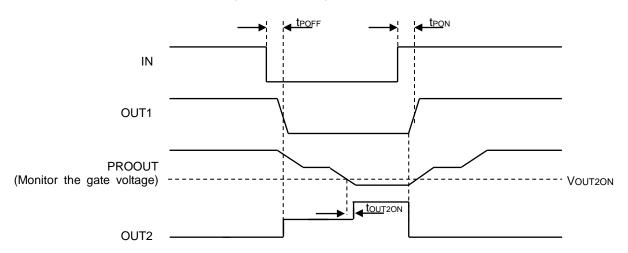
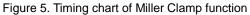


Figure 4. Block diagram of Miller Clamp function





## BM6101FV-C

## 2) Fault status output

This function is used to output a fault signal from the FLT pin when a fault occurs (i.e., when the undervoltage lockout function (UVLO), short current protection function (SCP) or thermal protection function is activated) and hold the Fault signal until the set Fault output holding time is completed. The Fault output holding time tFLTRLs is given as the following equation with the settings of capacitor CFLTRLs and resistor RFLTRLs connected to the FLTRLS pin. For example, when CFLTRLs is set to  $0.01 \mu$ F and RFLTRLs is set to  $200 k\Omega$ , the holding time will be set to 2 ms.

tfltrls [ms]= Cfltrls [ $\mu$ F]•Rfltrls [k $\Omega$ ]

To set the fault output holding time to "0" ms, only connect the resistor RFLTRLS.

Status	FLT pin		
Normal	Hi-Z		
Fault occurs	L		

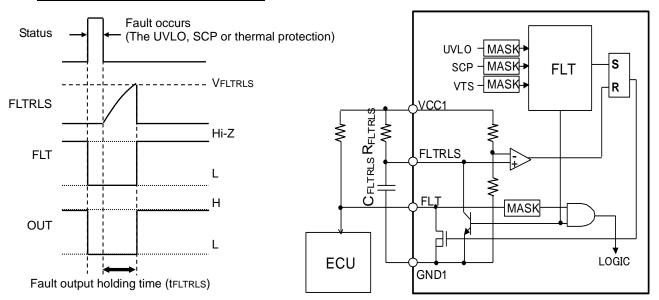
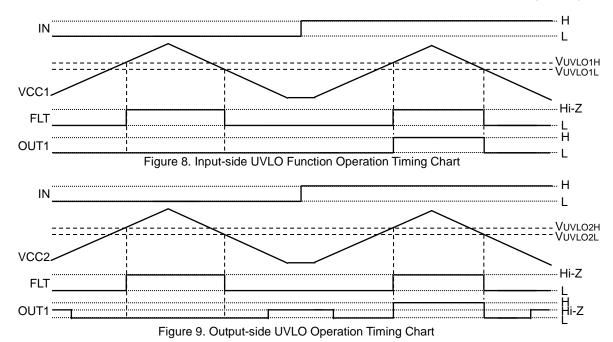


Figure 6. Fault Status Output Timing Chart



#### 3) Undervoltage Lockout (UVLO) function

The BM6101FV-C incorporates the undervoltage lockout (UVLO) function both on the low and the high voltage sides. When the power supply voltage drops to the UVLO ON voltage, the OUT pin and the FLT pin both will output the "L" signal. When the power supply voltage rises to the UVLO OFF voltage, these pins will be reset. However, during the fault output holding time set in "2) Fault status output" section, the OUT pin and the FLT pin will hold the "L" signal. In addition, to prevent malfunctions due to noises, mask time tuvLo1MSK and tuvLo2MSK are set on both low and high voltage sides.



4) Short current protection function (SCP, DESAT)

When the SCPIN pin voltage exceeds a voltage set with the VSCDET parameter, the SCP function will be activated. When the SCP function is activated, the OUT1 pin voltage will be set to the "Hi-Z" level first, and then the PROOUT pin voltage to the "L" level (soft turn-off).Next, after  $t_{STO}$  has passed after the short-circuit current falls below the threshold value, OUT pin becomes L and PROOUT pin becomes L. Finally, when the fault output holding time set in "2) fault status output" section on page 5 is completed, the SCP function will be released.

When OUT1=L or Hi-Z, internal MOSFET connected to SCPIN pin turns ON to discharge CBLANK. When OUT1=H, internal MOSFET connected to SCPIN turns OFF.

 $V_{COLLECTOR}/V_{DRAIN}$  which Desaturation Protection starts operation ( $V_{DESAT}$ ) and the blanking time ( $t_{BLANK}$ ) can be calculated by the formula below;

$$V_{DESAT}[V] = V_{SCDET} \bullet \frac{R3 + R2}{R3} - V_{F_D}$$

$$V_{CC2_{MIN}}[V] > V_{SCDET} \bullet \frac{R3 + R2 + R1}{R3}$$

$$t_{BLANKoutemal}[s] = -\frac{R2 + R1}{R3 + R2 + R1} \bullet R3 \bullet (C_{BLANK} + 27 \bullet 10^{-12}) \bullet \ln(1 - \frac{R3 + R2 + R1}{R3} \bullet \frac{V_{SCDET}}{V_{CC2}}) + 0.65 \bullet 10^{-6}$$

		Reference Value	
Vdesat	R1	R2	R3
4.0V	15 kΩ	39 kΩ	6.8 kΩ
4.5V	15 kΩ	43 kΩ	6.8 kΩ
5.0V	15 kΩ	36 kΩ	5.1 kΩ
5.5V	15 kΩ	39 kΩ	5.1 kΩ
6.0V	15 kΩ	43 kΩ	5.1 kΩ
6.5V	15 kΩ	62 kΩ	6.8 kΩ
7.0V	15 kΩ	68 kΩ	6.8 kΩ
7.5V	15 kΩ	82 kΩ	7.5 kΩ
8.0V	15 kΩ	91 kΩ	8.2 kΩ
8.5V	15 kΩ	82 kΩ	6.8 kΩ
9.0V	15 kΩ	130 kΩ	10 kΩ
9.5V	15 kΩ	91 kΩ	6.8 kΩ
10.0V	15 kΩ	130 kΩ	9.1 kΩ

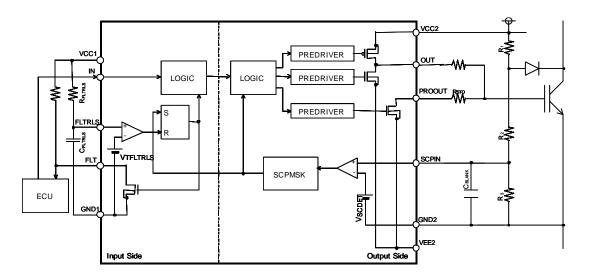


Figure 10. Block Diagram for DESAT

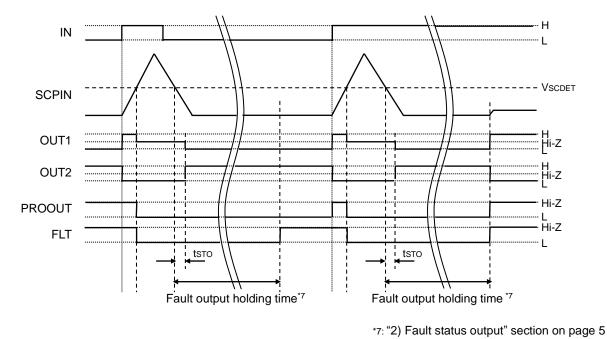
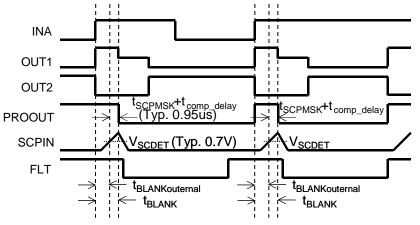


Figure 11. SCP Operation Timing Chart



tcomp\_delay: Detection delay time of internal comparator

Figure 12. DESAT sequence

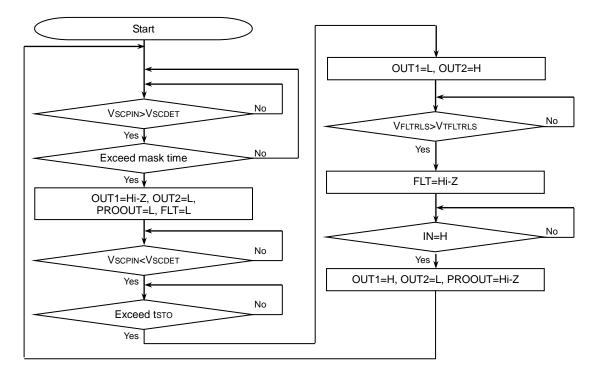


Figure 13. SCP Operation Status Transition Diagram

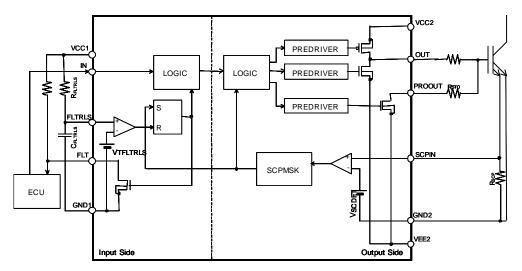
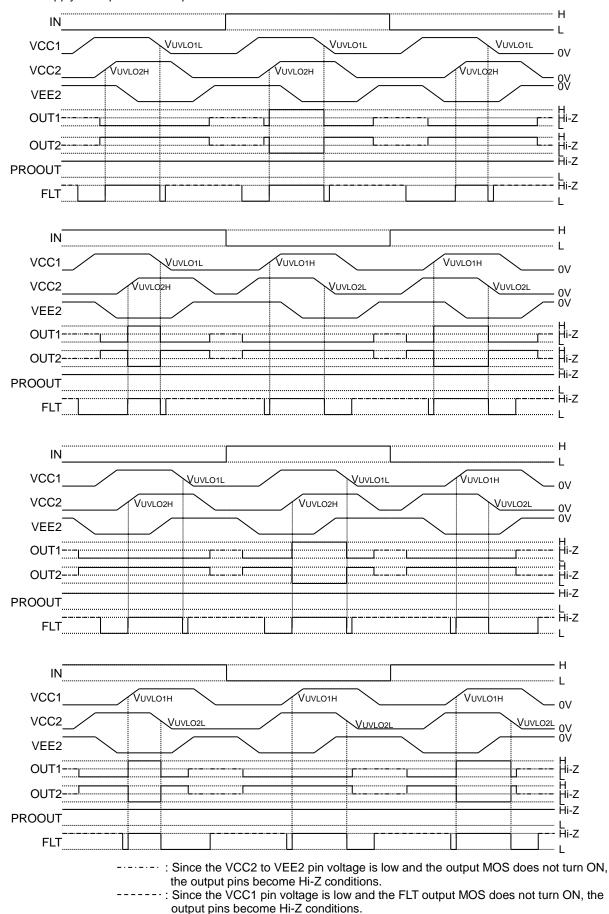


Figure 14. Block Diagram for SCP

## 5) I/O condition table

			-	-	Inpu	It	-	-	-			Output		
No.	Status	VCC1	VCC2	V T S I N	S C P I N	F L T	E N A	I N B	I N A	P R O O U T	0 U T 1	0 U T 2	P R O U T	F L T
1	SCP	Х	Х	Х	Н	Х	Х	Х	Х	Х	Hi-Z	L	L	L
2	VCC1UVLO	UVLO	х	Х	L	Х	Х	Х	Х	Н	L	Hi-Z	Hi-Z	L
3	VCCTUVLO	UVLO	Х	Х	L	Х	Х	Х	Х	L	L	Н	Hi-Z	L
4	VCC2UVLO	х	UVLO	Х	L	Х	Х	Х	Х	Н	L	Hi-Z	Hi-Z	L
5	VCC20VLO	х	UVLO	Х	L	Х	Х	Х	Х	L	L	Н	Hi-Z	L
6	Thormal protoction	0	0	L	L	Х	Х	Х	Х	Н	L	Hi-Z	Hi-Z	L
7	Thermal protection	0	0	L	L	Х	Х	Х	Х	L	L	Н	Hi-Z	L
8	FLT external input	0	0	н	L	L	Х	Х	Х	Н	L	Hi-Z	Hi-Z	Hi-Z
9		0	0	н	L	L	Х	Х	Х	L	L	Н	Hi-Z	Hi-Z
10	Disable	0	0	Н	L	Н	Н	Х	Х	Н	L	Hi-Z	Hi-Z	Hi-Z
11	Diodolo	0	0	н	L	Н	Н	Х	Х	L	L	Н	Hi-Z	Hi-Z
12	Non-invert operation	0	0	н	L	Н	L	L	L	Н	L	Hi-Z	Hi-Z	Hi-Z
13	L input	0	0	н	L	Н	L	L	L	L	L	Н	Hi-Z	Hi-Z
14	Non-invert operation H input	0	0	Н	L	Н	L	L	Н	х	Н	L	Hi-Z	Hi-Z
15	Invert operation L input	0	0	Н	L	Н	L	Н	L	х	Н	L	Hi-Z	Hi-Z
16	Invert operation H	0	0	н	L	Н	L	Н	Н	Н	L	Hi-Z	Hi-Z	Hi-Z
17	input	0	0	Н	L	Н	L	Н	Н	L	L	Н	Hi-Z	Hi-Z

O: VCC1 or VCC2 > UVLO, X:Don't care



6) Power supply startup / shutoff sequence

Figure 15. Power supply startup / shutoff sequence

## Absolute Maximum Ratings

Parameter	Symbol	Limits	Unit
Input-side supply voltage	V <sub>CC1</sub>	-0.3 to +7.0 <sup>*1</sup>	V
Output-side positive supply voltage	V <sub>CC2</sub>	-0.3 to +30.0*2	V
Output-side negative supply voltage	V <sub>EE2</sub>	-15.0 to +0.3 <sup>*2</sup>	V
Maximum difference between output-side positive and negative voltages	V <sub>MAX2</sub>	36.0	V
INA, INB, ENA pin input voltage	Vin	-0.3 to +VCC1+0.3 or 7.0*1	V
FLT pin input voltage	V <sub>FLT</sub>	-0.3 to +VCC1+0.3 or 7.0*1	V
FLTRLS pin input voltage	V <sub>FLTRLS</sub>	-0.3 to +VCC1+0.3 or 7.0*1	V
VTSIN pin input voltage	VVTSIN	-0.3 to +10.0 <sup>*2</sup>	V
SCPIN pin input voltage	V <sub>SCPIN</sub>	-0.3 to +10.0*2	V
VREG pin output current	I <sub>VREG</sub>	10	mA
OUT1 pin output current (DC)	Iout1	0.4*3	А
OUT1 pin output current (Peak 1us)	I <sub>OUT1PEAK</sub>	5.0	А
OUT2 pin output current (DC)	IOUT2	0.1 <sup>*3</sup>	А
OUT2 pin output current (Peak 1us)	Iout2peak	1	А
PROOUT pin output current	Iproout	0.2*3	А
FLT output current	IFLT	10	mA
Power dissipation	Pd	1.19 <sup>*4</sup>	W
Operating temperature range	T <sub>opr</sub>	-40 to +125	°C
Storage temperature range	T <sub>stg</sub>	-55 to +150	°C
Junction temperature *1 Relative to GND1.	Tjmax	+150	°C

1 Relative to GND1.

\*2 Relative to GND2.
\*3 Should not exceed Pd and Tj=150°C.

\*4 Derate above Ta=25°C at a rate of 9.5mW/°C. Mounted on a glass epoxy of 70 mm × 70 mm × 1.6 mm.

## Recommended Operating Ratings

Parameter	Symbol	Min.	Max.	Units
Input-side supply voltage	Vcc1 <sup>*5</sup>	4.5	5.5	V
Output-side positive supply voltage	V <sub>CC2</sub> *6	14	24	V
Output-side negative supply voltage	Vee2*6	-12	0	V
Maximum difference between output-side positive and negative voltages	V <sub>MAX2</sub>	14	32	V
VTSIN pin input voltage	Vvtsin <sup>*6</sup>	0	5	V

\*5 Relative to GND1.\*6 Relative to GND2.

#### Insulation related characteristics

Parameter	Symbol	Characteristic	Units
Insulation Resistance (V <sub>IO</sub> =500V)	Rs	>109	Ω
Insulation Withstand Voltage / 1min	Viso	2500	Vrms
Insulation Test Voltage / 1sec	V <sub>ISO</sub>	3000	Vrms

## •Electrical Characteristics

(Unless otherwise specified Ta=-40°C to 125°C, V<sub>CC1</sub>=4.5V to 5.5V, V<sub>CC2</sub>=14V to 24V, V<sub>EE2</sub>=-12V to 0V)

(Unless otherwise specified Ta=-2	1				1	
Parameter General	Symbol	Min.	Тур.	Max.	Unit	Conditions
Input side circuit current 1	I <sub>CC1</sub>	0.20	0.45	0.70	mA	OUT=L
Input side circuit current 2	Icc12	0.20	0.45	0.70	mA	OUT=H
Input side circuit current 3		1.2	2.0	2.8	mA	INA=10kHz, Duty=50%
•	ICC13					
Input side circuit current 4	ICC14	2.1	3.5	4.9	mA mA	INA=20kHz, Duty=50%
Output side circuit current 1	ICC21	1.9	3.2	4.5	mA	VCC2=14V, OUT=L
Output side circuit current 2	ICC22	1.3	2.1	2.9	mA	VCC2=14V, OUT=H
Output side circuit current 3	I <sub>CC23</sub>	2.1	3.5	4.9	mA	VCC2=18V, OUT=L
Output side circuit current 4	ICC24	1.4	2.4	3.4	mA	VCC2=18V, OUT=H
Output side circuit current 5	ICC25	2.4	4.0	5.6	mA	VCC2=24V, OUT=H
Output side circuit current 6 Logic block	ICC26	1.6	2.7	3.8	mA	VCC2=24V, OUT=L
Logic high level input voltage	VINH	0.7 × V <sub>CC1</sub>	_	V <sub>CC1</sub>	V	INA, INB, ENA, FLT
Logic low level input voltage	VINH	0.7 × V <sub>CC1</sub>	-	0.3 × V <sub>CC1</sub>	V	INA, INB, ENA, FLT
Logic pull-down resistance		25	50	100	kΩ	INA, INB, ENA, FEI
•		25	50	100	kΩ	ENA
Logic pull-up resistance	R <sub>INU</sub>					
Logic input mask time		80	130	180	ns	INA, INB
ENA, FLT mask time	<b>t</b> FLTMSK	4	10	20	μs	ENA, FLT
Output	D	0.7	4.0	1.0	0	
OUT1 ON resistance (Source)	R <sub>ONH</sub>	0.7	1.8	4.0	Ω	IOUT=40mA
OUT1 ON resistance (Sink)	Ronl	0.4	0.9	2.0	Ω	IOUT=40mA VCC2=18V
OUT1 maximum current	Ιουτμαχ	3.0	4.5	-	A	Design assurance
PROOUT ON resistance	Ronpro	0.4	0.9	2.0	Ω	Iproout=40mA
Turn ON time	<b>t</b> PON	180	265	350	ns	
Turn OFF time	<b>t</b> POFF	180	265	350	ns	
Propagation distortion	<b>t</b> PDIST	-60	0	60	ns	tpoff - tpon
Rise time	t <sub>RISE</sub>	-	50	100	ns	10nF between OUT1-VEE2
Fall time	tFALL	-	50	100	ns	10nF between OUT1-VEE2
OUT2 ON resistance (Source)	R <sub>ON2H</sub>	2.0	4.5	9.0	Ω	IOUT2=40mA
OUT2 ON resistance (Sink)	Ron2L	1.5	3.5	7.0	Ω	IOUT2=40mA
OUT2 ON threshold voltage	Vout20N	1.8	2	2.2	V	Relative to VEE2
OUT2 output delay time	tout20N	-	15	50	ns	
VREG output voltage	VREG	9	10	11	V	Relative to VEE2
Common Mode Transient Immunity	CM	100	-	-	kV/μs	Design assurance
Protection functions	-			I		
VCC1 UVLO OFF voltage	Vuvlo1h	4.05	4.25	4.45	V	
VCC1 UVLO ON voltage	VUVLO1L	3.95	4.15	4.35	V	
VCC1 UVLO mask time	tuvlo1MSK	4	10	30	μs	
VCC2 UVLO OFF voltage	VUVLO2H	11.5	12.5	13.5	V	
VCC2 UVLO ON voltage	VUVLO2H VUVLO2L	10.5	12.5	12.5	V	
VCC2 UVLO mask time		4	11.5	30		
SCPIN Input voltage			0.1	0.22	μs V	
· •		-			V	ISCPIN=1mA
SCP detection voltage	VSCDET	0.665	0.700	0.735	V	
SCP detection mask time	tscpmsk	0.55	0.8	1.05		
Soft turn OFF release time	tsto	30	4 70	110	μs	
Thermal detection voltage	VTSDET	1.60	1.70	1.80	V	
Thermal detection mask time	tтямяк	4	10	30	μs	
FLT output low voltage	Vfltl	-	0.18	0.40	V	IFLT=5mA
FLTRLS threshold	VTFLTRLS	0.64 × V <sub>CC1</sub>	0.64 × V <sub>CC1</sub>	0.64 × V <sub>CC1</sub>	V	
		-0.1		+0.1		

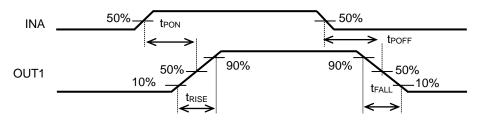


Figure 16. INA-OUT1 Timing Chart

#### **OUL1577** Ratings Table

Following values are described in UL Report.

Parameter	Values	Units	Conditions
Side 1 (Input Side) Circuit Current	0.45	mA	VCC1=5.0V, OUT1=L
Side 2 (Output Side) Circuit Current	3.5	mA	VCC2=18V, VEE2=0V, OUT1=L
Side 1 (Input Side) Consumption Power	2.25	mW	VCC1=5.0V, OUT1=L
Side 2 (Output Side) Consumption Power	63	mW	VCC2=18V, VEE2=0V, OUT1=L
Isolation Voltage	2500	Vrms	
Maximum Operating (Ambient) Temperature	125	°C	
Maximum Junction Temperature	150	°C	
Maximum Strage Temperature	150	°C	
Maximum Data Transmission Rate	2.5	MHz	

## ●Typical Performance Curves

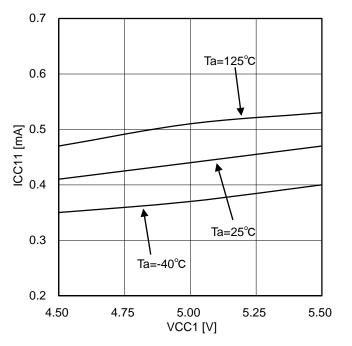
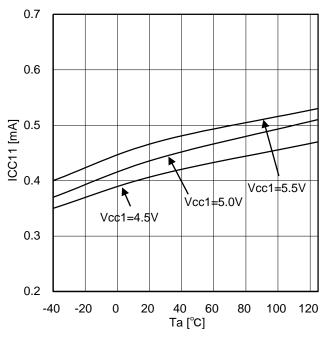
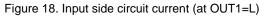


Figure 17. Input side circuit current (at OUT1=L)





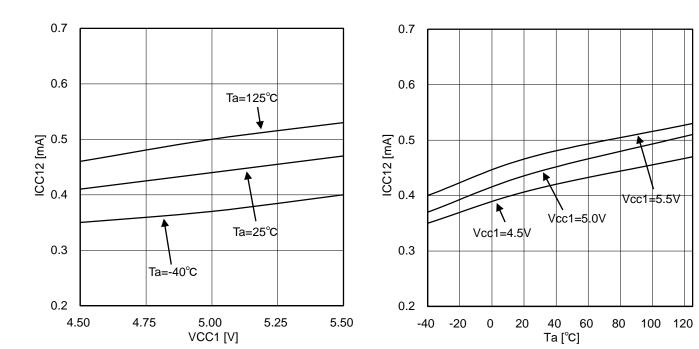


Figure 19. Input side circuit current (at OUT1=H)

(at INA=10kHz and Duty=50%)

Figure 20. Input side circuit current (at OUT1=H)

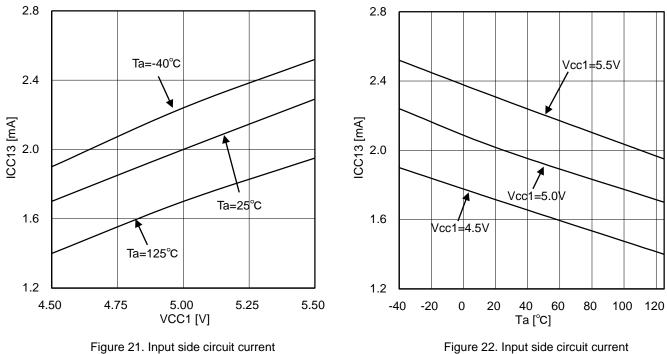


Figure 22. Input side circuit current (at INA=10kHz and Duty=50%)

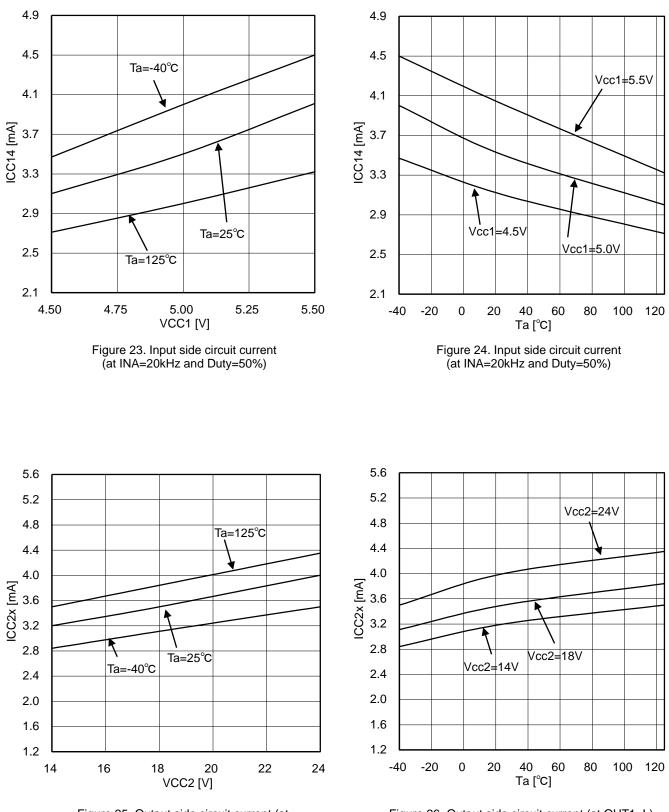
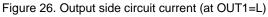
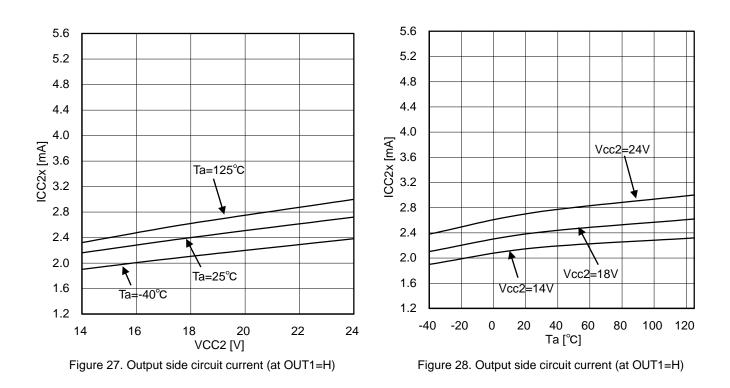


Figure 25. Output side circuit current (at OUT1=L)





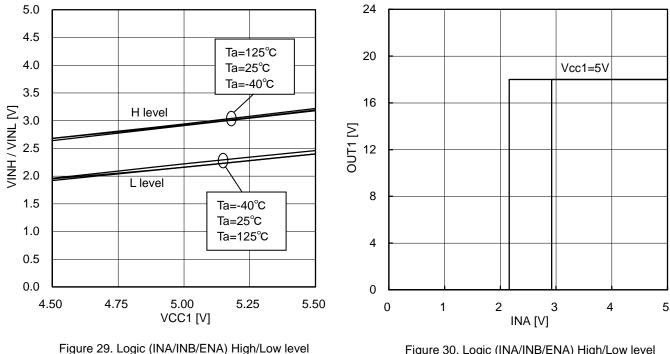


Figure 30. Logic (INA/INB/ENA) High/Low level input voltage at Ta=25 $^\circ\!\!C$ 

input voltage

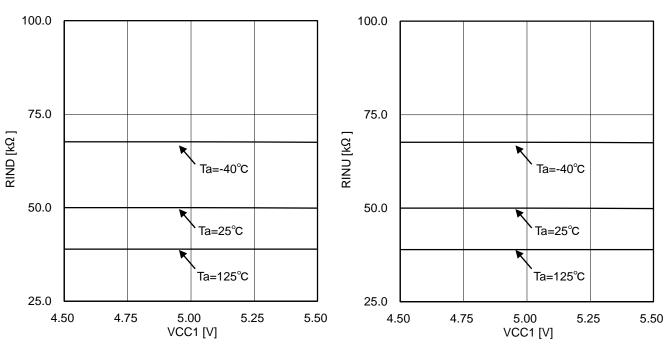
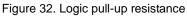
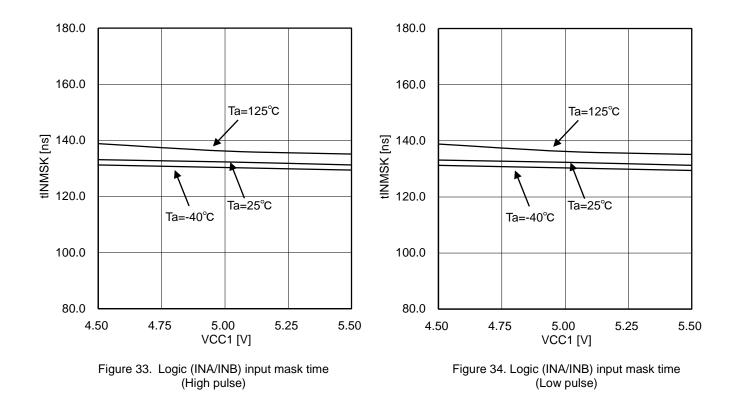
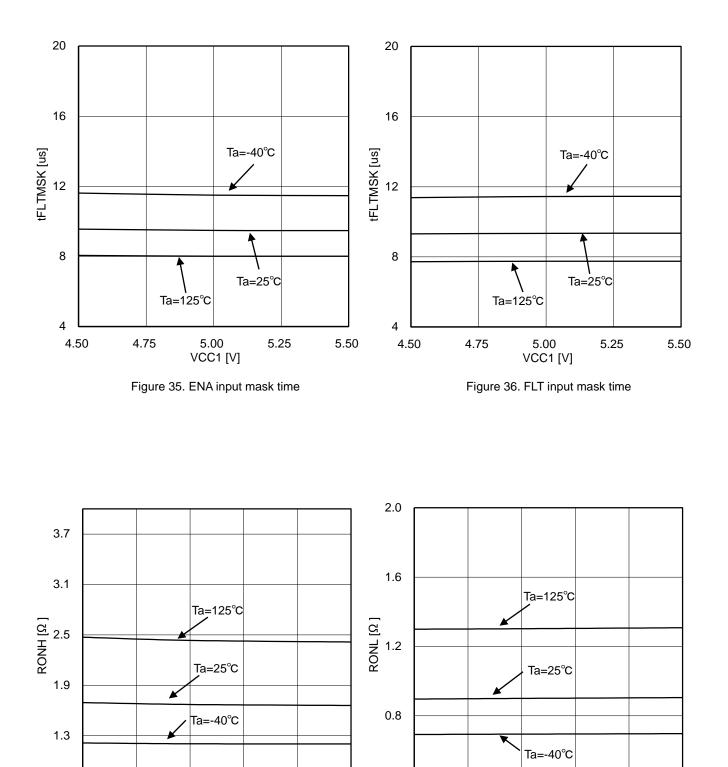


Figure 31. Logic pull-down resistance





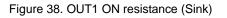


VCC2 [V]

20

22

18



VCC2 [V]

20

22

24

18

16

0.7 L 14 0.4

14

16

24

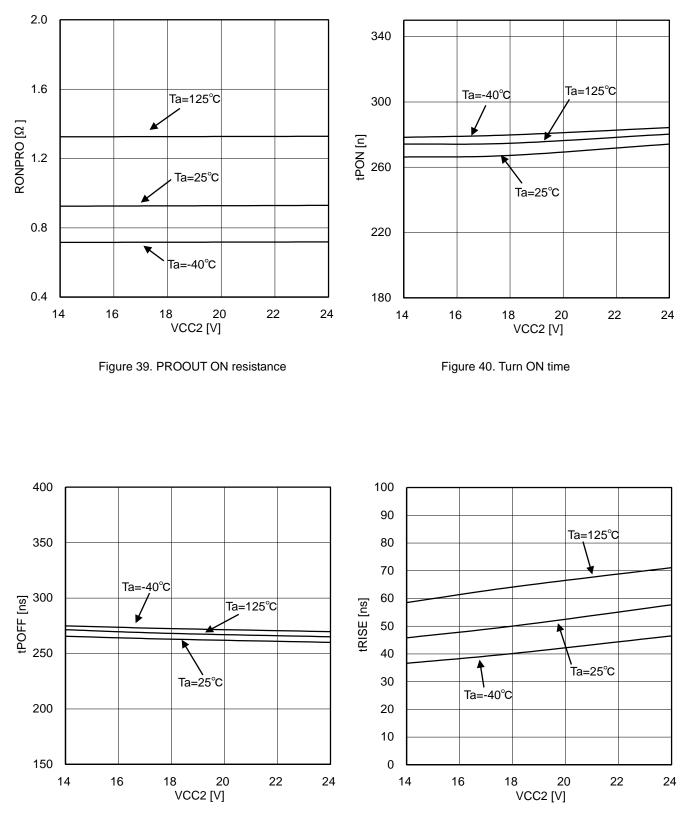


Figure 41. Turn OFF time

Figure 42. Rise time (10nF between OUT1-VEE2)

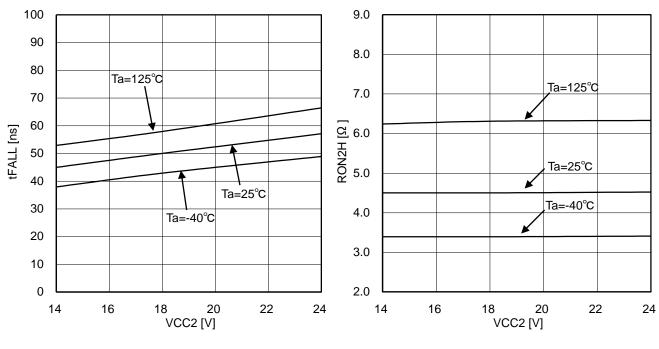


Figure 43. Fall time (10nF between OUT1-VEE2)



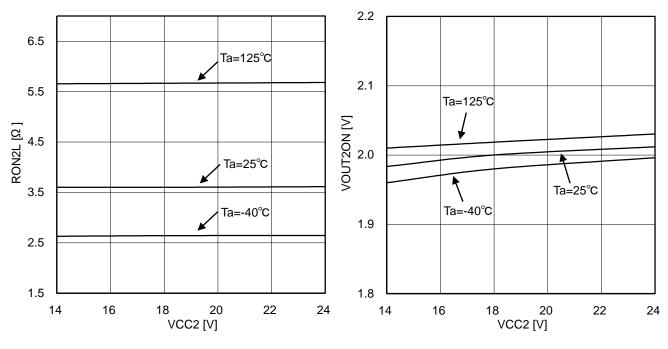
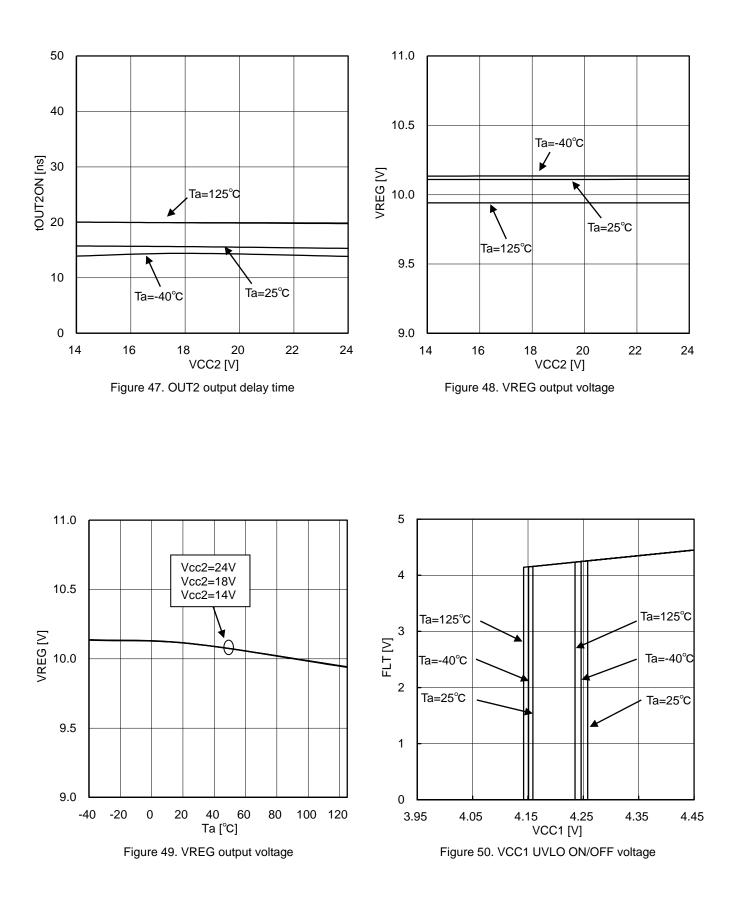
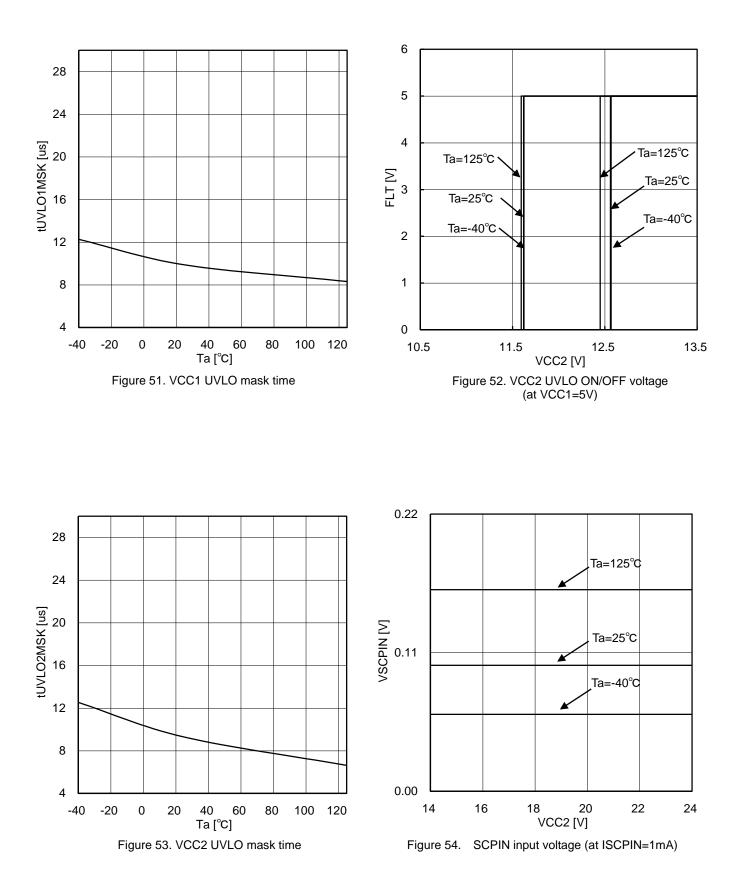
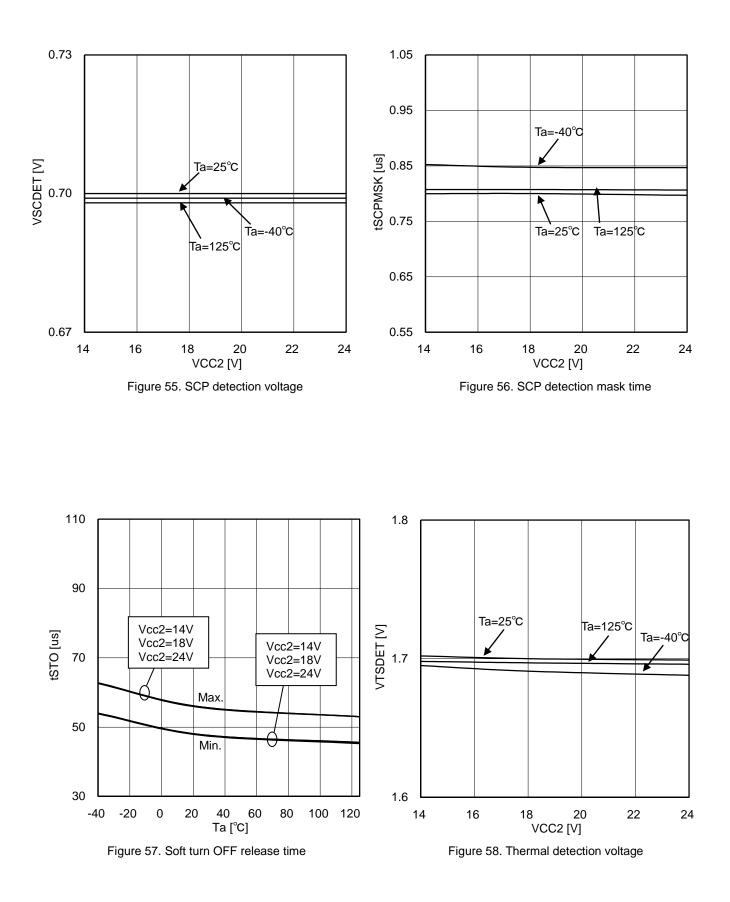


Figure 45. OUT2 ON resistance (Sink)

Figure 46. OUT2 ON threshold voltage







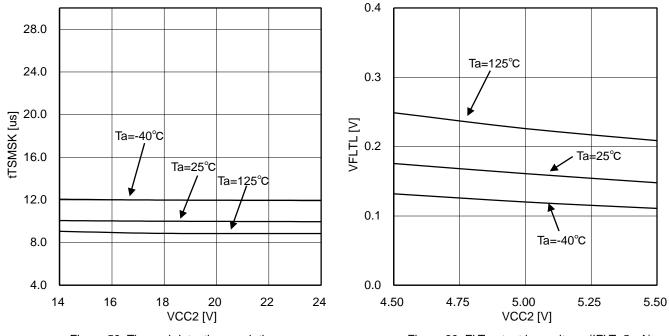
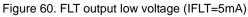
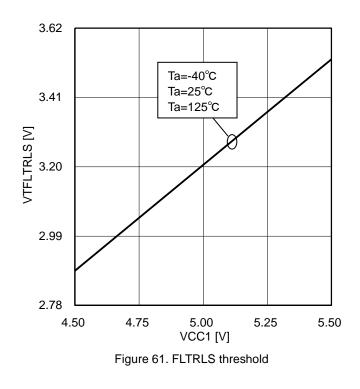
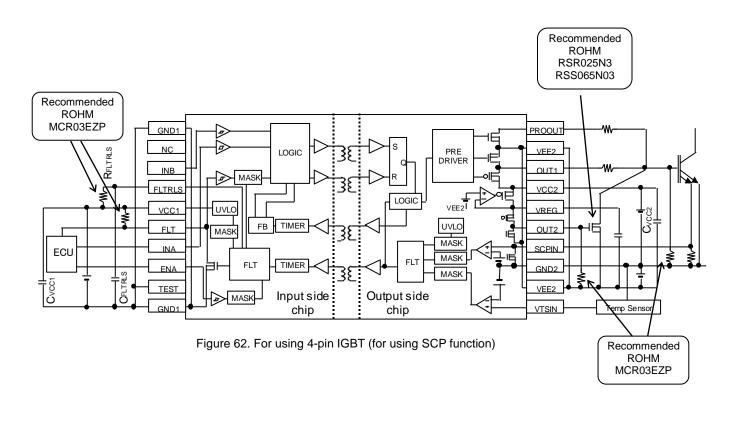


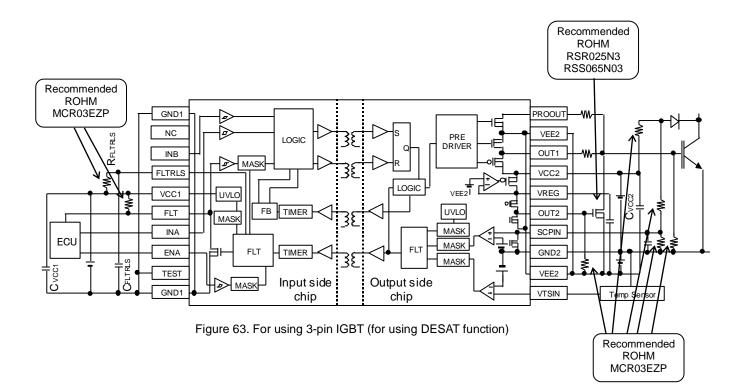
Figure 59. Thermal detection mask time





## Selection of Components Externally Connected





## Power Dissipation

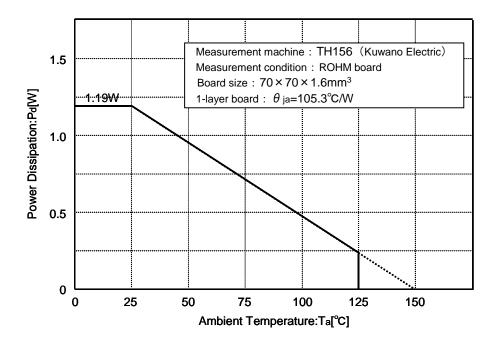


Figure 64. SSOP-B20W Derating Curve

#### Thermal design

Please design that the IC's chip temperature Tj is not over 150°C, while considering the IC's power consumption (W), package power (Pd) and ambient temperature (Ta). When Tj=150°C is exceeded the functions as a semiconductor do not operate and some problems (ex. Abnormal operation of various parasitic elements and increasing of leak current) occur. Constant use under these circumstances leads to deterioration and eventually IC may destruct. Tjmax=150°C must be strictly obeyed under all circumstances.

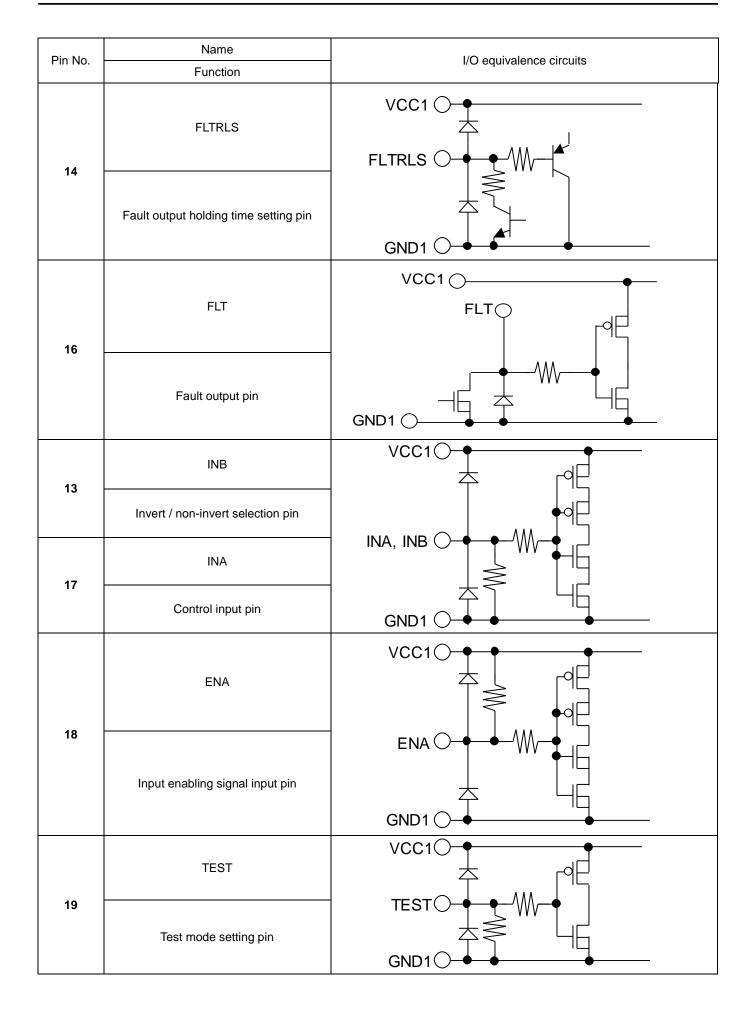
The IC's consumed power (P) can be estimated roughly with following equation.

```
P = VCC1 \cdot ICC1 + VCC2 \cdot IGND2 + (VCC2 + VEE2) \cdot (ICC2 \cdot IGND2) + ION^2 \cdot RONH \cdot tON \cdot fPWM + IOFF^2 \cdot RONL \cdot tOFF \cdot fPWM
```

fPWM : PWM frequency ION : OUT pin outflow current when OUT is H state. tON : Current outflow time from OUT pin when OUT is H state. IOFF : OUT pin inflow current when OUT is L state. toFF : Current inflow time to OUT pin when OUT is L state.

## ●I/O equivalence circuits

	Name	I/O equivalence circuits			
Pin No.	Function				
1	VTSIN	VCC2 Internal pow er supply			
	Thermal detection pin				
4	SCPIN				
	Short current detection pin	VEE2			
5	OUT2	Internal pow er supply			
	MOS FET control pin for Miller Clamp				
6	VREG				
	Power supply pin for driving MOS FET for Miller Clamp	· · · · · · · · · · · · · · · · · · ·			
8	OUT				
	Output pin				
10	PROOUT				
	Soft turn-off pin	PROOUT			



## Operational Notes

- (1) Absolute maximum ratings
  - An excess in the absolute maximum ratings, such as supply voltage, temperature range of operating conditions, etc., can break down the devices, thus making impossible to identify breaking mode, such as a short circuit or an open circuit. If any over rated values will expect to exceed the absolute maximum ratings, consider adding circuit protection devices, such as fuses.
- (2) Connecting the power supply connector backward

Connecting of the power supply in reverse polarity can damage IC. Take precautions when connecting the power supply lines. An external direction diode can be added.

(3) Power supply Lines

Design PCB layout pattern to provide low impedance GND and supply lines. To obtain a low noise ground and supply line, separate the ground section and supply lines of the digital and analog blocks. Furthermore, for all power supply terminals to ICs, connect a capacitor between the power supply and the GND terminal. When applying electrolytic capacitors in the circuit, not that capacitance characteristic values are reduced at low temperatures.

(4) GND1 Potential

The potential of GND1 pin must be minimum potential in all operating conditions. (Input side ; 11pin to 20pin) (5) VEE2 Potential

The potential of VEE2 pin must be minimum potential in all operating conditions. (Output side ; 1pin to 10pin) (6) Thermal design

Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions. (7) Inter-pin shorts and mounting errors

When attaching to a printed circuit board, pay close attention to the direction of the IC and displacement. Improper attachment may lead to destruction of the IC. There is also possibility of destruction from short circuits which can be caused by foreign matter entering between outputs or an output and the power supply or GND.

(8) Operation in a strong electric field

Use caution when using the IC in the presence of a strong electromagnetic field as doing so may cause the IC to malfunction.

(9) Inspection of the application board

During inspection of the application board, if a capacitor is connected to a pin with low impedance there is a possibility that it could cause stress to the IC, therefore an electrical discharge should be performed after each process. Also, as a measure again electrostatic discharge, it should be earthed during the assembly process and special care should be taken during transport or storage. Furthermore, when connecting to the jig during the inspection process, the power supply should first be turned off and then removed before the inspection.

(10) Input terminal of IC

Between each element there is a P+ isolation for element partition and a P substrate. This P layer and each element's N layer make up the P-N junction, and various parasitic elements are made up.

For example, when the resistance and transistor are connected to the terminal as shown in figure 65,

OWhen GND>(Terminal A) at the resistance and GND>(Terminal B) at the transistor (NPN), the P-N junction operates as a parasitic diode.

OAlso, when GND>(Terminal B) at the transistor (NPN), The parasitic NPN transistor operates with the N layers of other elements close to the aforementioned parasitic diode.

Because of the IC's structure, the creation of parasitic elements is inevitable from the electrical potential relationship. The operation of parasitic elements causes interference in circuit operation, and can lead to malfunction and destruction. Therefore, be careful not to use it in a way which causes the parasitic elements to operate, such as by applying voltage that is lower than the GND (P substrate) to the input terminal.

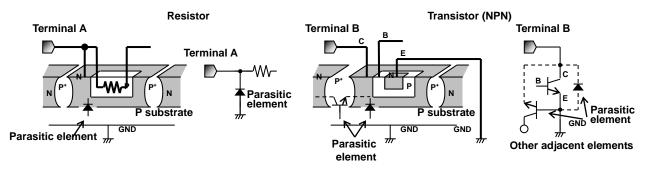
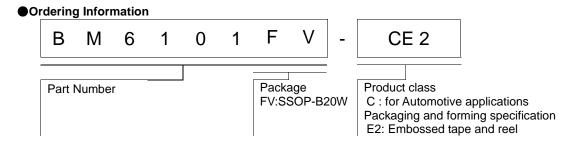


Figure 65. Pattern Diagram of Parasitic Element

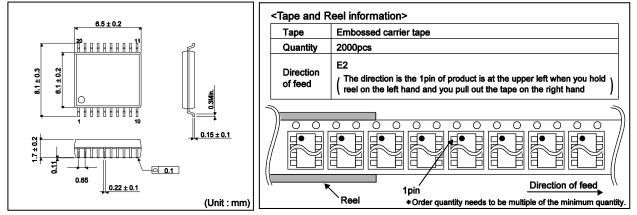
#### (11) Ground Wiring Patterns

When using both small signal and large current GND patterns, it is recommended to isolate the two ground patterns, placing a single ground point at the application's reference point so that the pattern wiring resistance and voltage variations caused by large currents do not cause variations in the small signal ground voltage. Be careful not to change the GND wiring pattern potential of any external components, either.

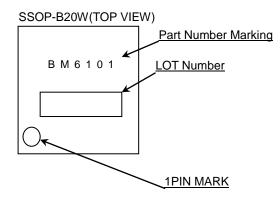


#### Physical Dimension Tape and Reel Information

## SSOP-B20W



## Marking Diagram



## Revision History

Date	Revision	Changes
24.Jun.2013	001	New Release
20.May.2015	002	P.1 Features Adding item (UL1577 Recognized, AEC-Q100 Qualified) P.4 Description of Pins Adding TEST pin
25.Dec.2015	003	P.13 Adding UL1577 Rating Table

# Notice

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1. If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment <sup>(Note 1)</sup>, aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

JAPAN	USA	EU	CHINA	
CLASSII	CLASSⅢ	CLASS II b	CLASSII	
CLASSⅣ	CLASSI	CLASSⅢ	CLASSII	

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:

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[b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

- 3. Our Products are not designed under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
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  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
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  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
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  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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## BM6101FV-C - Web Page

Part Number	BM6101FV-C
Package	SSOP-B20W
Unit Quantity	2000
Minimum Package Quantity	2000
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes